

27. (New) A device according to claim 24 wherein said insulating film comprises silicon oxide.

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28. (New) A device according to claim 24 wherein at least one of said plurality of insulating layers in said interlayer insulating layer comprises a material selected from the group consisting of silicon nitride and organic resin.

29. (New) A device according to claim 24 wherein said low doped impurity region includes phosphorus at a dose of 0.1 to 5  $\times 10^{14}$  atoms/cm<sup>2</sup>.

30. (New) A device according to claim 24 wherein said high doped impurity region includes phosphorus at a dose of 0.2 to 5  $\times 10^{15}$  atoms/cm<sup>2</sup>.

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REMARKS

Entry of the above amendments to claim 1 and the addition of new claims 2-30 prior to further examination are requested.

Please apply any charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

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